

# *Comparison of Central Trackers for the ILC*



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4<sup>th</sup> Concept Collaboration

LCWS2008

11/18/2008

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# Performance Studies of 10000 events of 10muons single tracks

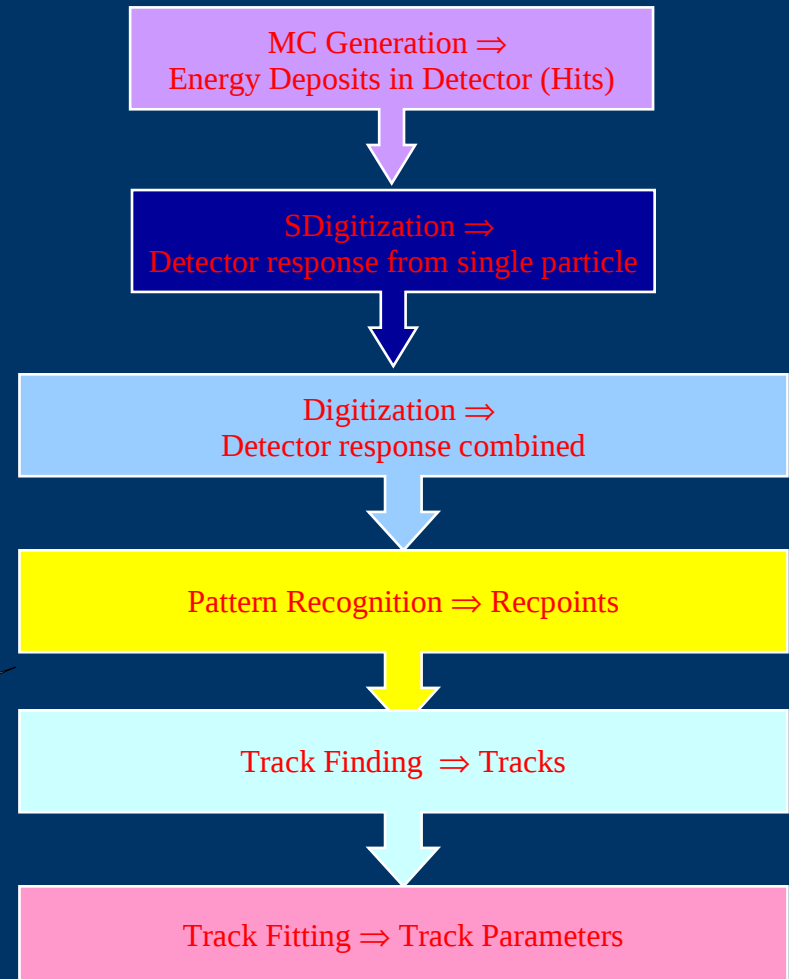
- P: [0,200] GeV
- $\theta$ : [0,180°] (flat  $\cos\theta$ )
- $\varphi$ : [0,360°]
- B: 3.5/5 Tesla

# *IlcRoot – The 4<sup>th</sup> Concept Framework*

## Simulation/recostruction

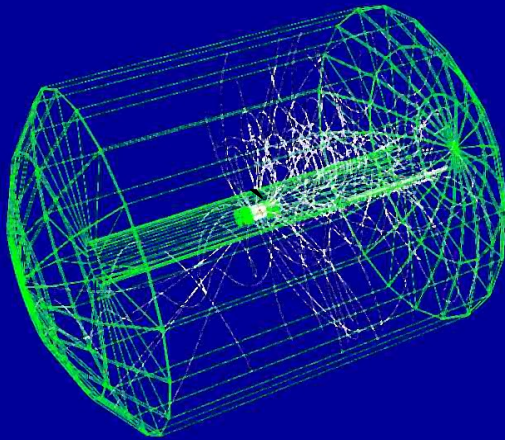
- Hits, Dig, SDig.
- With the Virtual MonteCarlo Interface is possible to use different MonteCarlo (G4, G3, Fluka ...)
- High flexibility (6 tracking detectors: 2 x VXD, TPC, DCH, SiD, SiPT)

See Ignatov's talk.



# DCH Layout

SiD with a  
scale's factor



VXD + CluCouDrift Chamber

- Full Digitization/Clusterization for VXD
- Paramatrized Digitization for DCH
- Prof. F. Grancagnolo and his CluCou group is working on the digitization

- 24 SuperLayer with 10 rings 240 rings
- 20  $\mu\text{m}$  W sense wires, in total 66000
- 80  $\mu\text{m}$  Al field wires, in total 156000
- Hexagonal cells
- Inner Radius: 19cm Router: 144cm
- $L=150$  at  $R=150$ ,  $L=424$  at  $R=19$
- Spherical EndCaps ( $R=2.24$ )
- Wires with Stereo Angles:  $\pm 55^\circ \div \pm 216^\circ$  mrad
- Drop,  $\delta=4\text{cm}$
- Filled with a mixture of Gas: 90% He + 10% iC<sub>4</sub>H<sub>10</sub>
- 3.5T Magnetic Field

# SiD – Strip Detector - Layout

Version SiD01-Polyhedra + SiD01

Guard ring: mm 0.07

Barrel Layers: 5

Total Tiles Barrel 7312

Wafer layout

Strip pitch 50  $\mu\text{m}$

Strip thickness (Si wafer) 300  $\mu\text{m}$

Strip length 93.31 mm

Tile width 93.531 mm

Carbonfiber in 0.228 mm

Rohacell tickness 3.175 mm

Carbonfiber out 0.228 mm

Si support 300  $\mu\text{m}$  x 6.667 mm x 63.8 mm

Kapton Layer 0.1 mm

Support layout

Carbon Fiber 500  $\mu\text{m}$

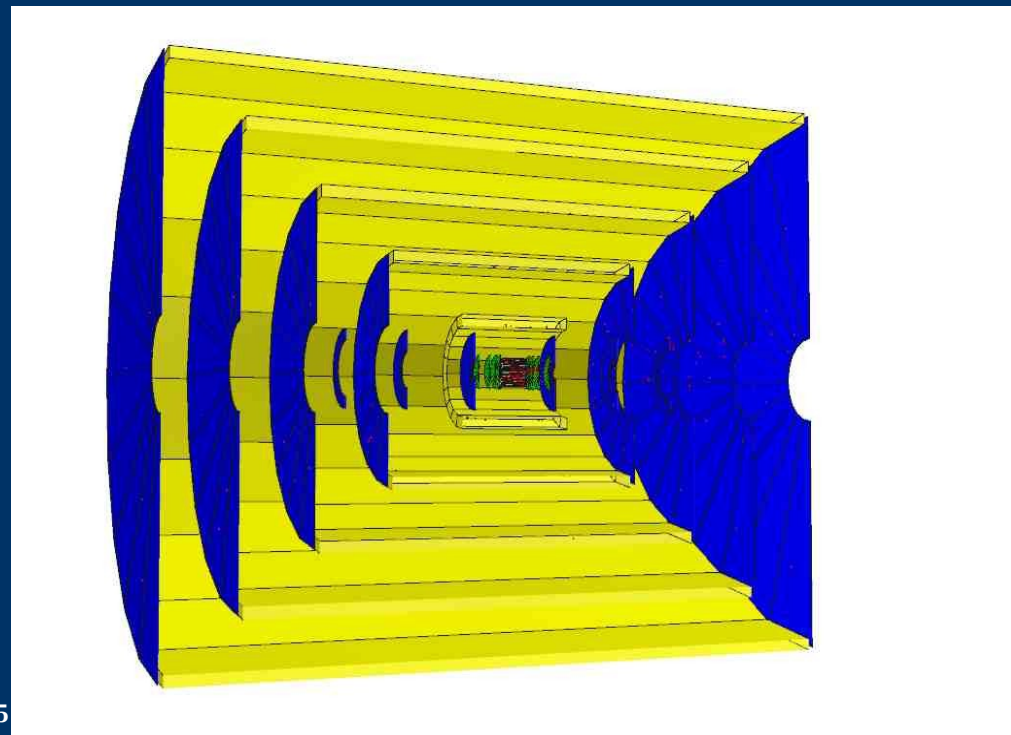
Rohacell 8.075 mm

Carbon Fiber 500  $\mu\text{m}$

Barrel Layer layout

Radial position (Barrel) cm 18.5-24.5; 44.1-50.1; 69.6-75.6; 95.2-101.2; 120.8-126.5

Z-length cm 53.4; 121.6; 189.6; 257.8; 326



Endcap rmin rmax z position in cm

1	18.5	48.6	62.9148
2	18.5	74.1	96.915515
3	18.5	99.7	131.016285
4	19.5	125.3	165.117005
5	2.78	16.67	20.59408
6	7.51	16.67	54.04408

Complete Digitization and Clusterization

Hits->SDigit->Digit->RecPoints 5

Barrel has single single sensor strips

Endcaps have double sensor strips with 17.5 mrad stereo angle

# SiPT – Pixel Detector- Layout

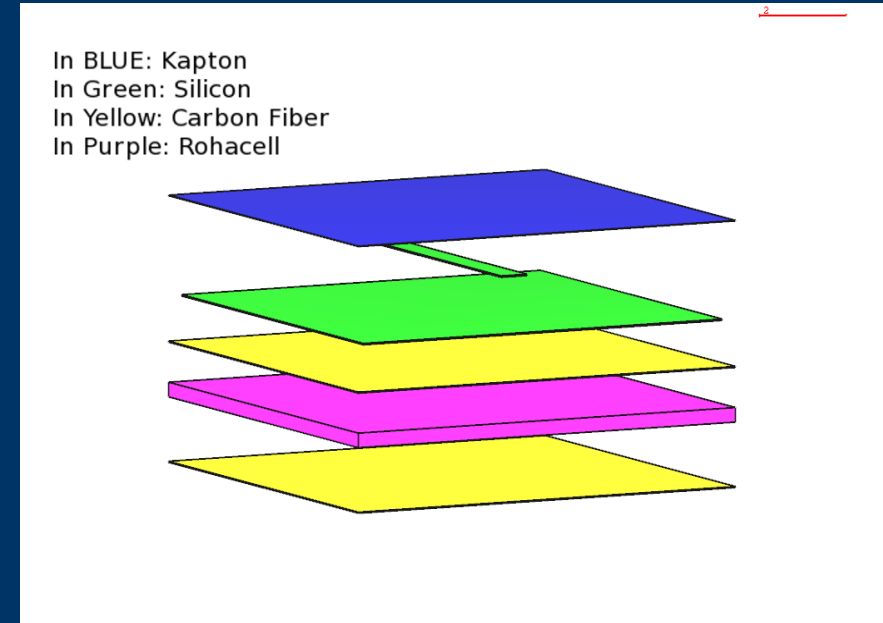
Same architecture of the strip detector.

Two very important difference are:

1) The size of pixel 50x50um!  
Increasing the number of tracking elements:

$O(10^{10})$  Vs  $O(10^7)$

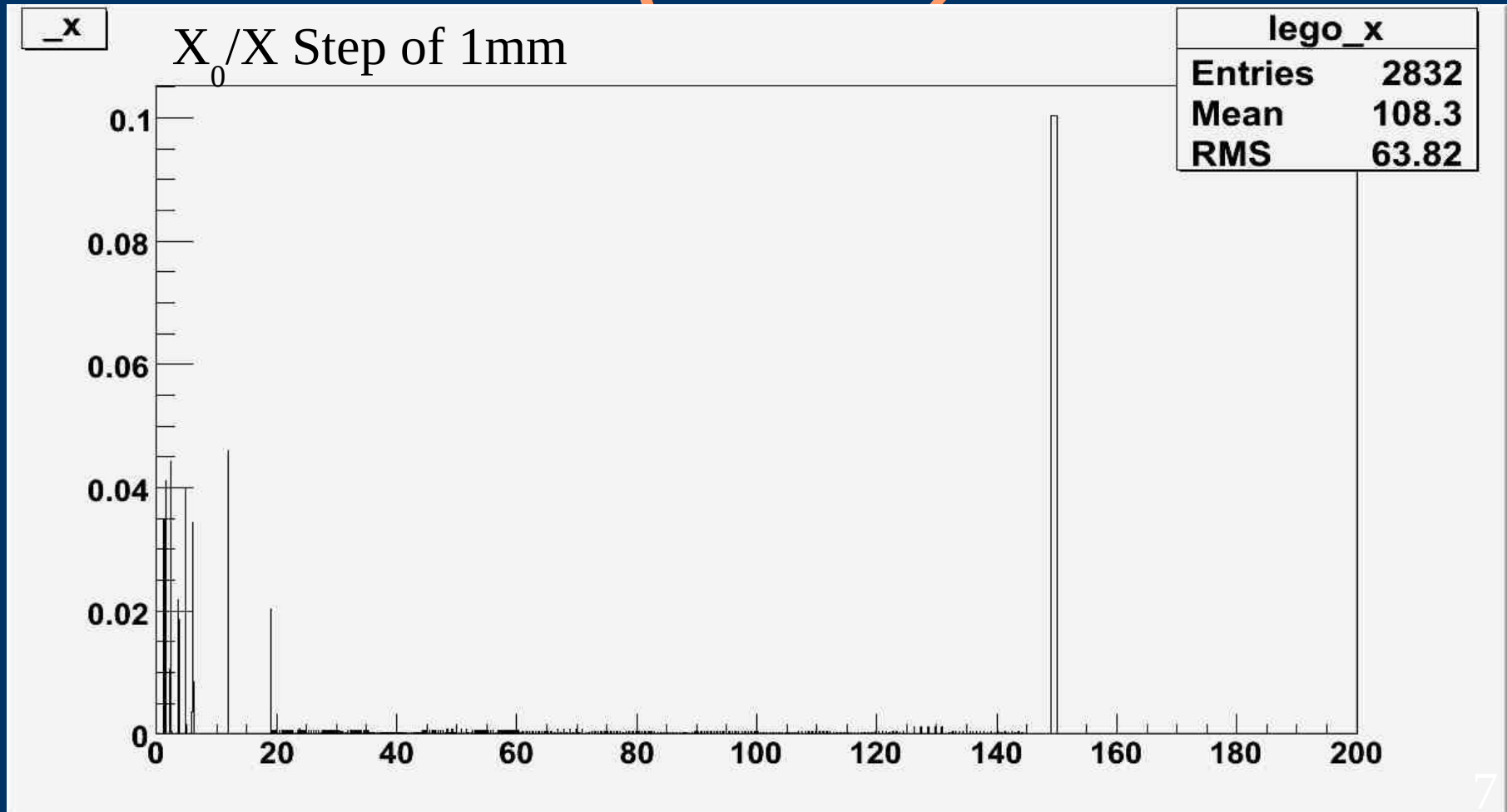
2) Difference in the thickness of the Silicon layers: 50um Vs 300um of the previous.



Wafer - Barrel Region

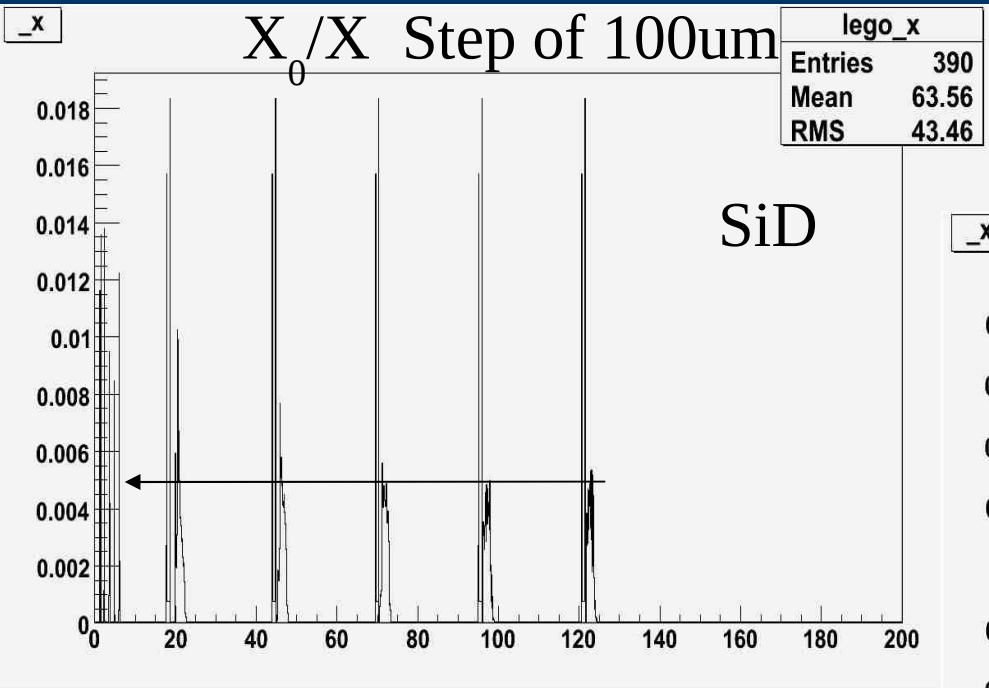
5T magnetic Field

# Material Budget – DCH + VXD ( $\theta=90^\circ$ )

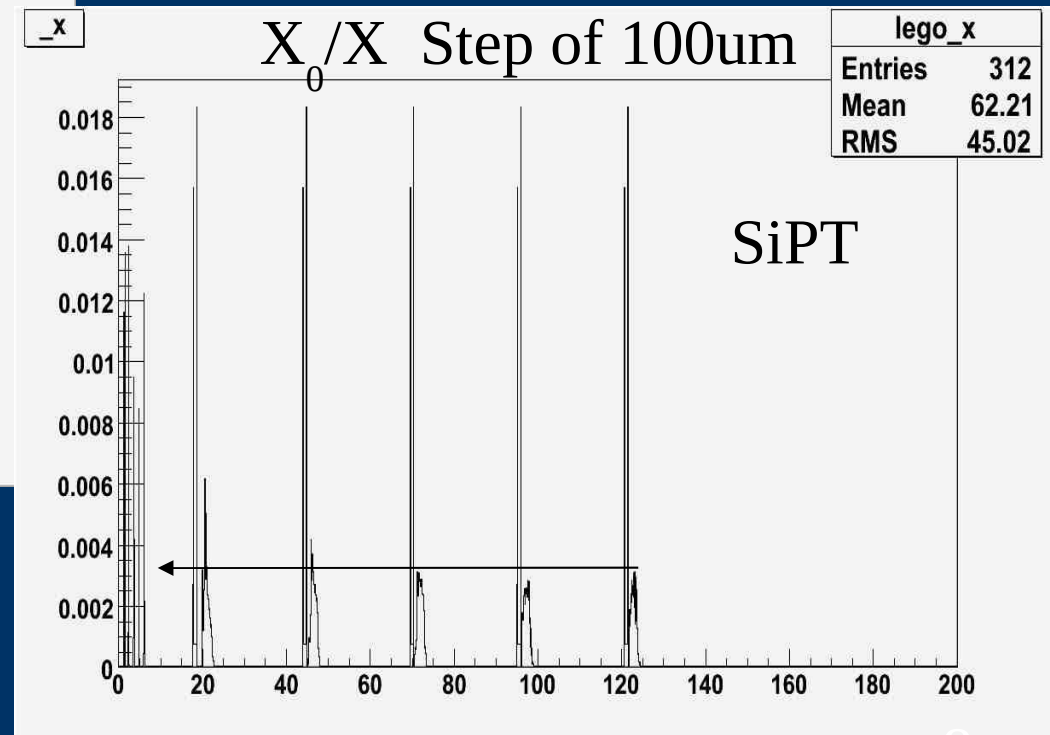


# Material Budget – Barrel Region SiD & SiPT ( $\theta=90^\circ$ )

Pixel Detector:  
less than SiD



Strip Detector:  
Very High Budget Material





# Material Budget (Summary)

- Beam Pipe: 0.18%  $X/X_0$
- VXD:
  - Detector & support: 0.8%  $X/X_0$

- **Drift Chamber**
- Gas [He-C<sub>4</sub>H<sub>10</sub>/90-10]: 0.15%
- Wires: 0.4%
- Vessel:
  - Inner wall: 0.1%  $X/X_0$
  - Outer wall: 2%  $X/X_0$
  - Endcaps (wires, pads, electronics & services included): 8%  $X/X_0$

## SiD StripTracker

- Barrel :6.21% (Si= 3.98% + Support=2.23%)
- Endcap Inner Disks: 2.93 %  $X/X_0$
- Endcap Outer Disks: 4.39-5.39% (with supports)  $X/X_0$

## SiPT PixelTracker

- Barrel :4.8% (Si= 2.6% + Support=2.2%)
- Endcap Inner Disks: 2.55 %  $X/X_0$
- Endcap Outer Disks: 3.78-4.28% (with supports)  $X/X_0$

# **Performance of the Simulated Detectors**

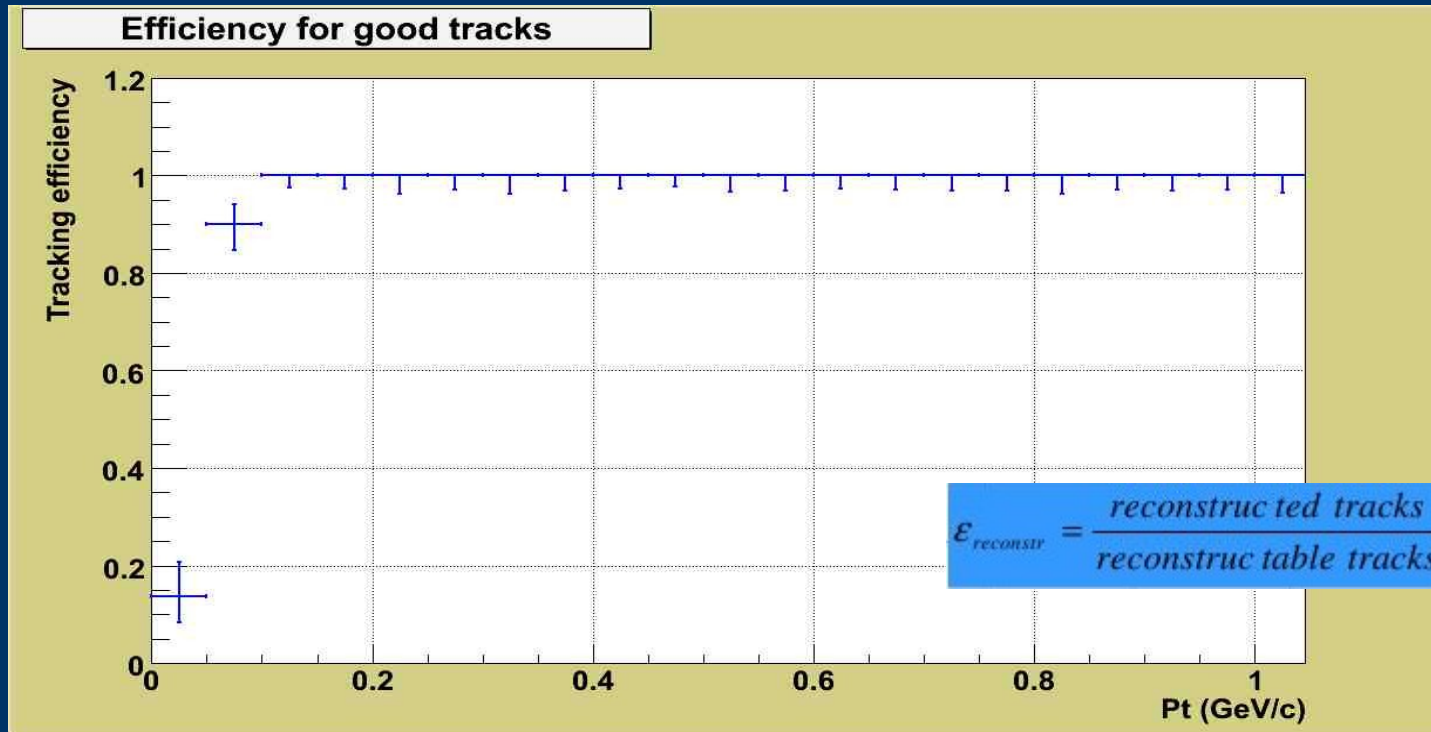
# *Efficiency Studies*

## *Reconstructable Tracks*

- $DCA(\text{true}) < 3.5 \text{ cm}$   
AND
- (At least 10 hits in DCH  
OR
- At least 4 hits in SiT + VXD)

$$\epsilon_{\text{geom}} = \frac{\text{Good Tracks}}{\text{Total Tracks Generated}}$$

# Efficiency Studies – DCH Low Pt

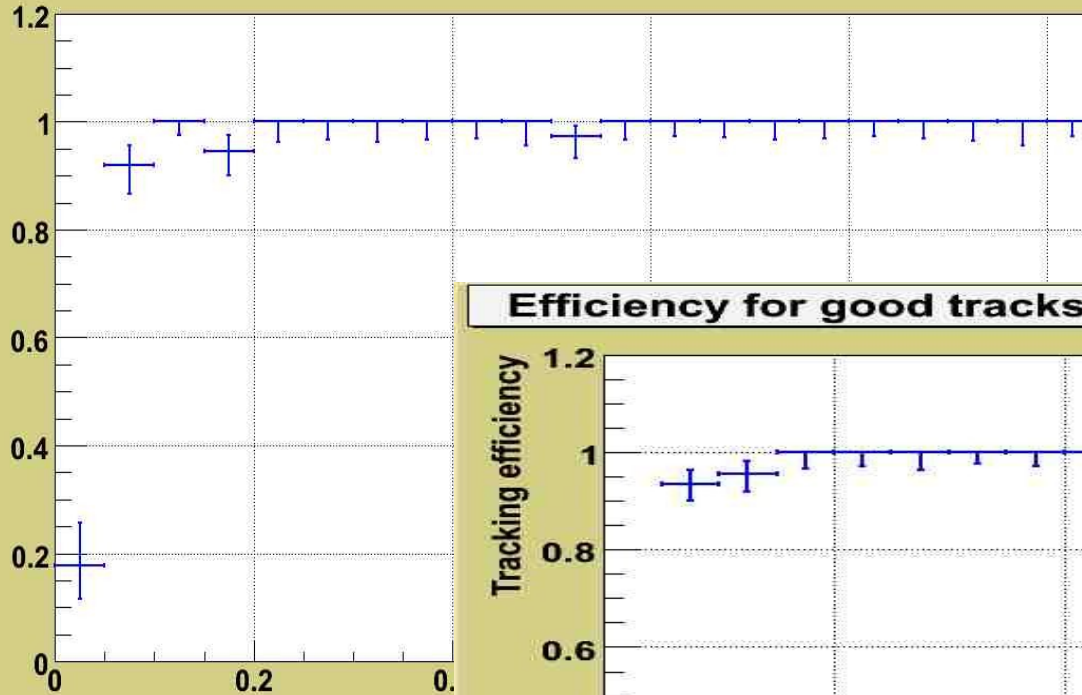


# Efficiency Studies SiD & SiPT

## Low Pt

Efficiency for good tracks

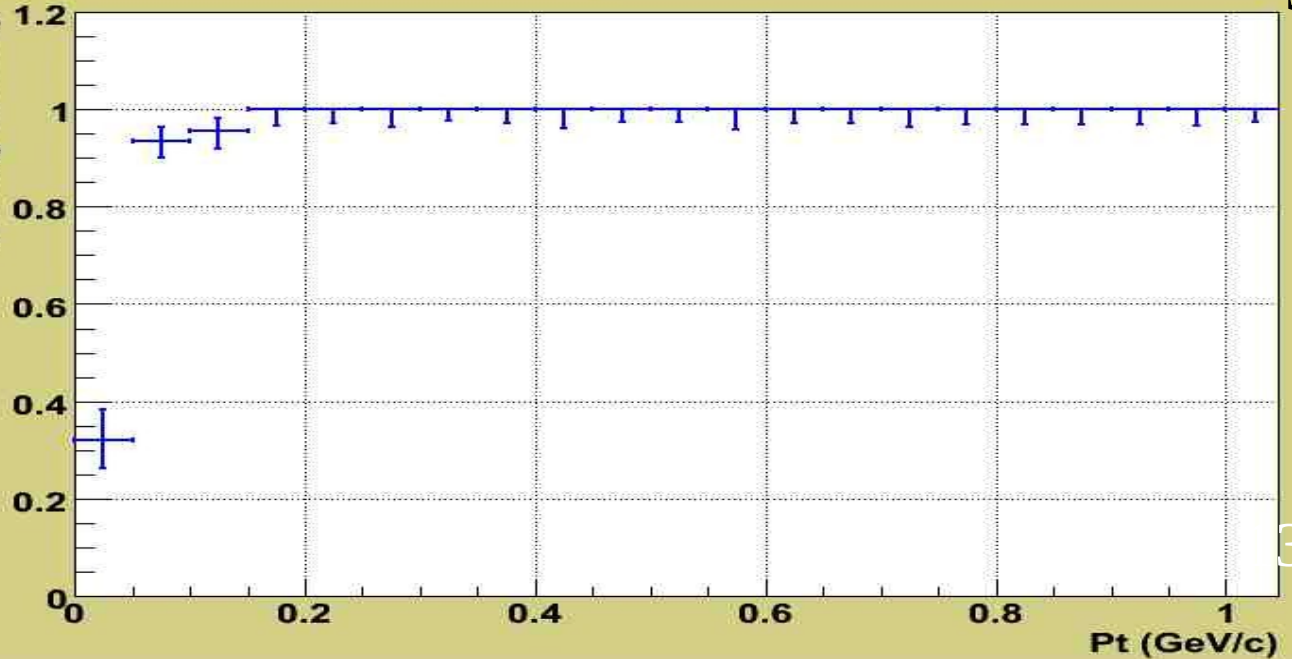
Tracking efficiency



SiD

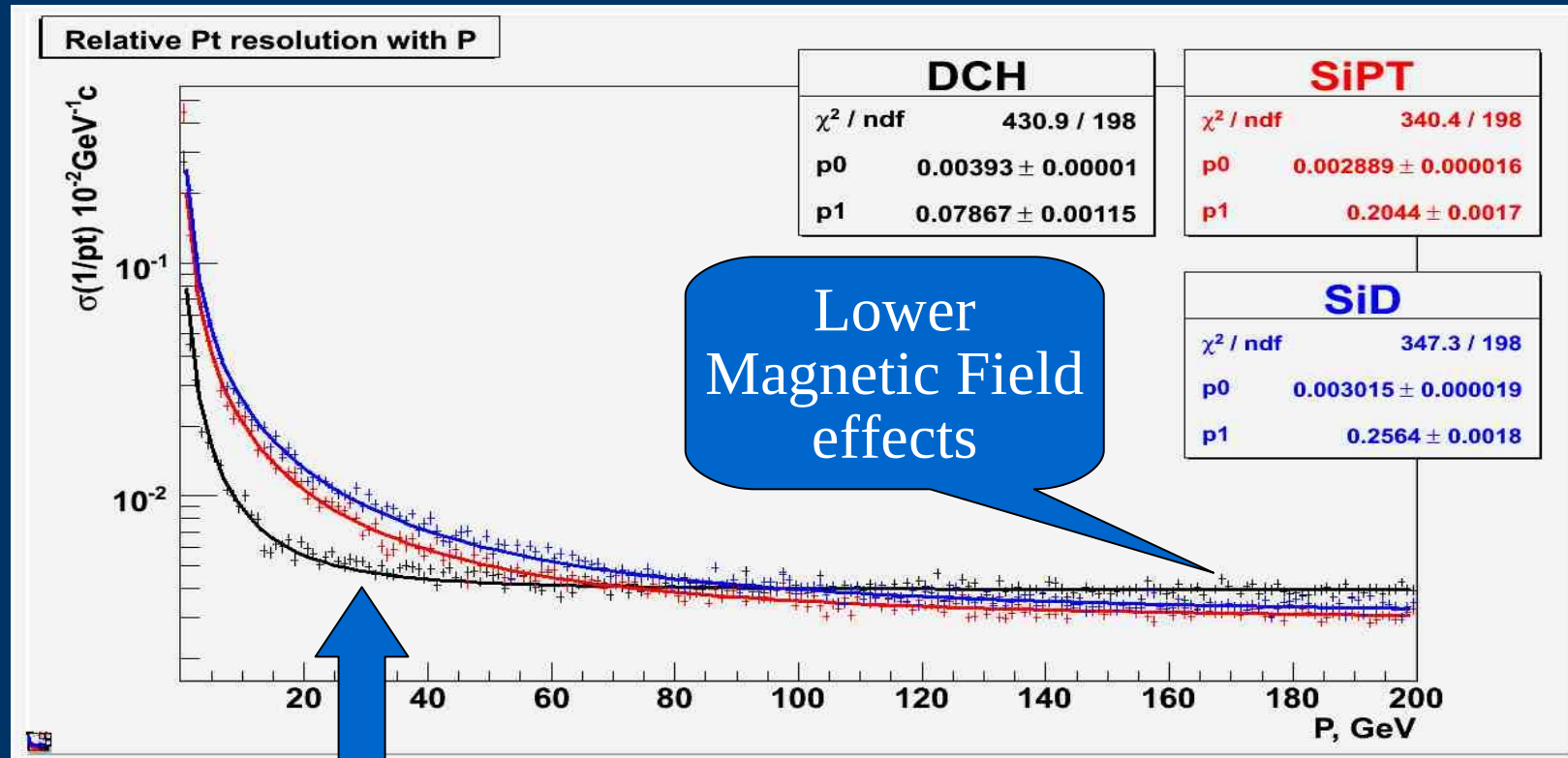
Efficiency for good tracks

Tracking efficiency



SiPT

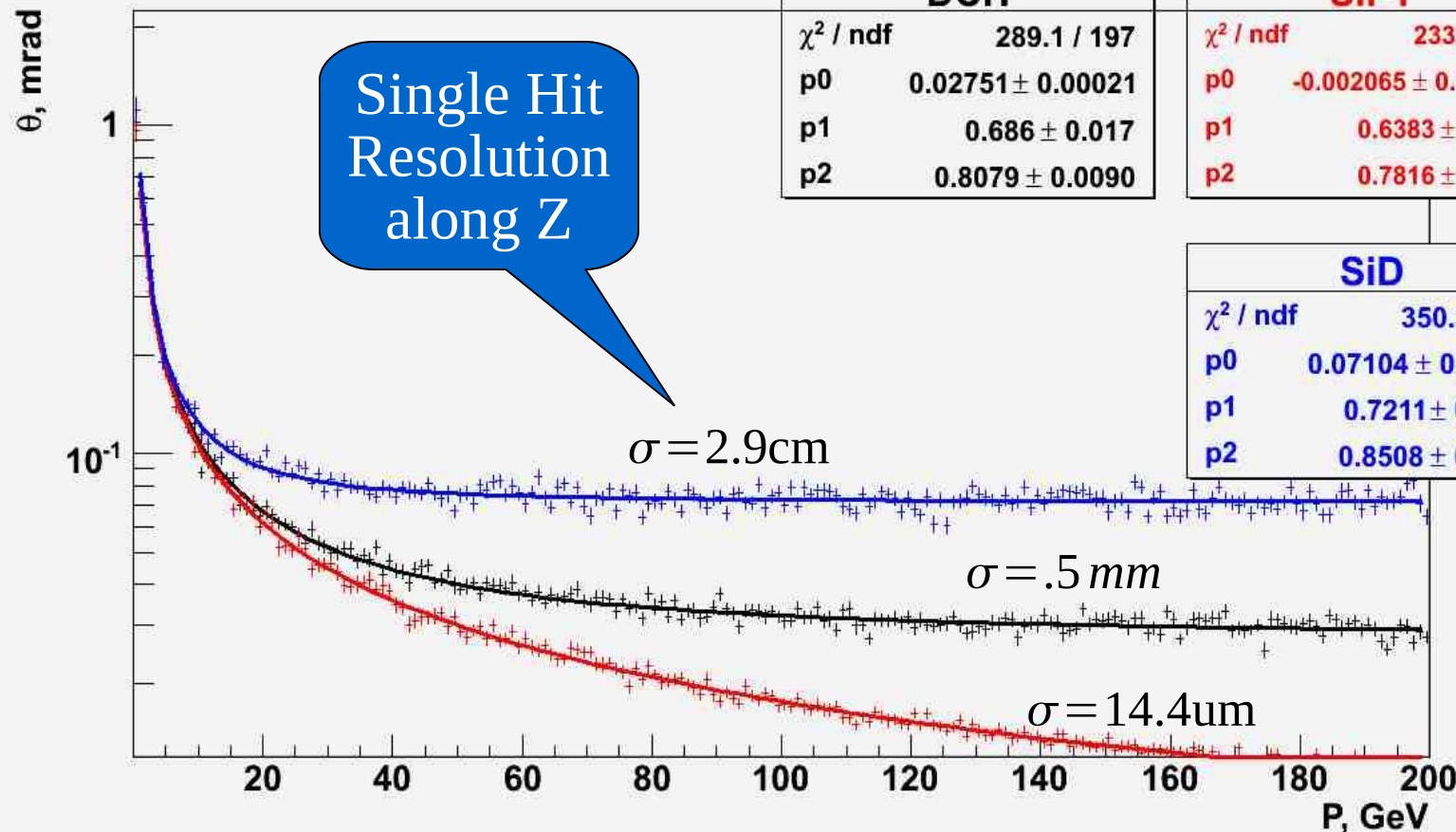
# Tracking Performance Pt Vs P



Reduced Multiple Scatter Effect!!!

# Tracking Performance Theta Vs P

Theta resolution with P



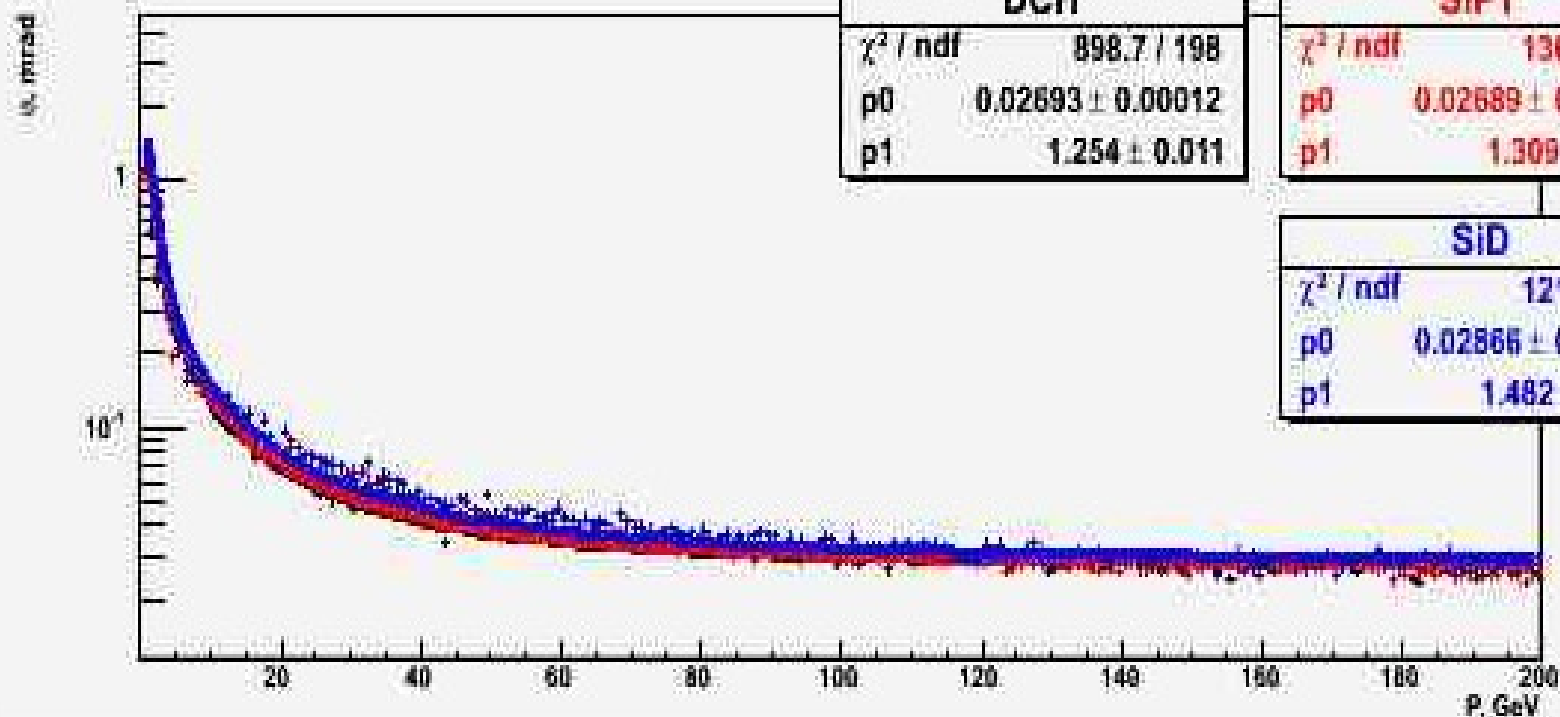
DCH	
$\chi^2 / \text{ndf}$	289.1 / 197
p0	$0.02751 \pm 0.00021$
p1	$0.686 \pm 0.017$
p2	$0.8079 \pm 0.0090$

SiPT	
$\chi^2 / \text{ndf}$	233.3 / 197
p0	$-0.002065 \pm 0.000388$
p1	$0.6383 \pm 0.0106$
p2	$0.7816 \pm 0.0043$

SiD	
$\chi^2 / \text{ndf}$	350.3 / 197
p0	$0.07104 \pm 0.00033$
p1	$0.7211 \pm 0.0215$
p2	$0.8508 \pm 0.0148$

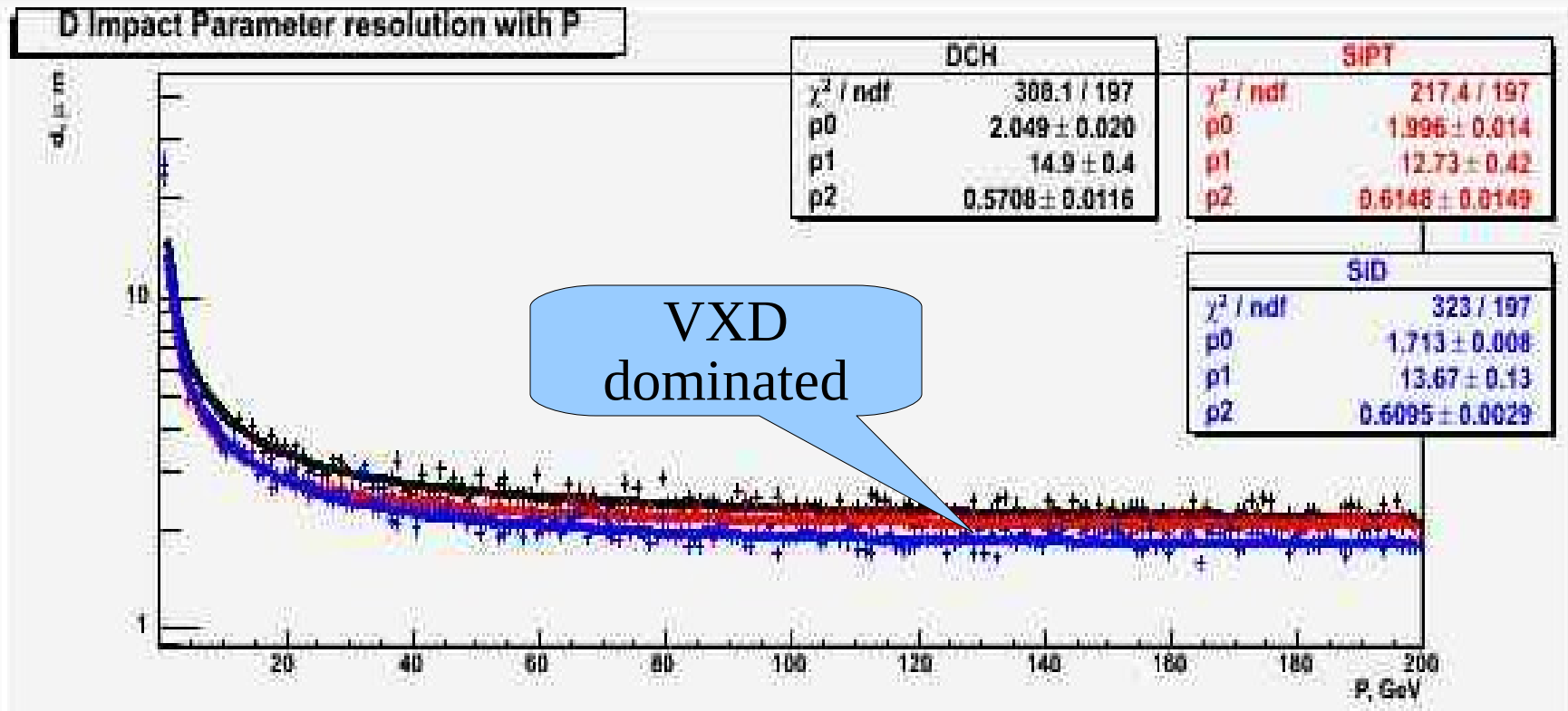
# Tracking Performance *Phi Vs P*

Phi resolution with P

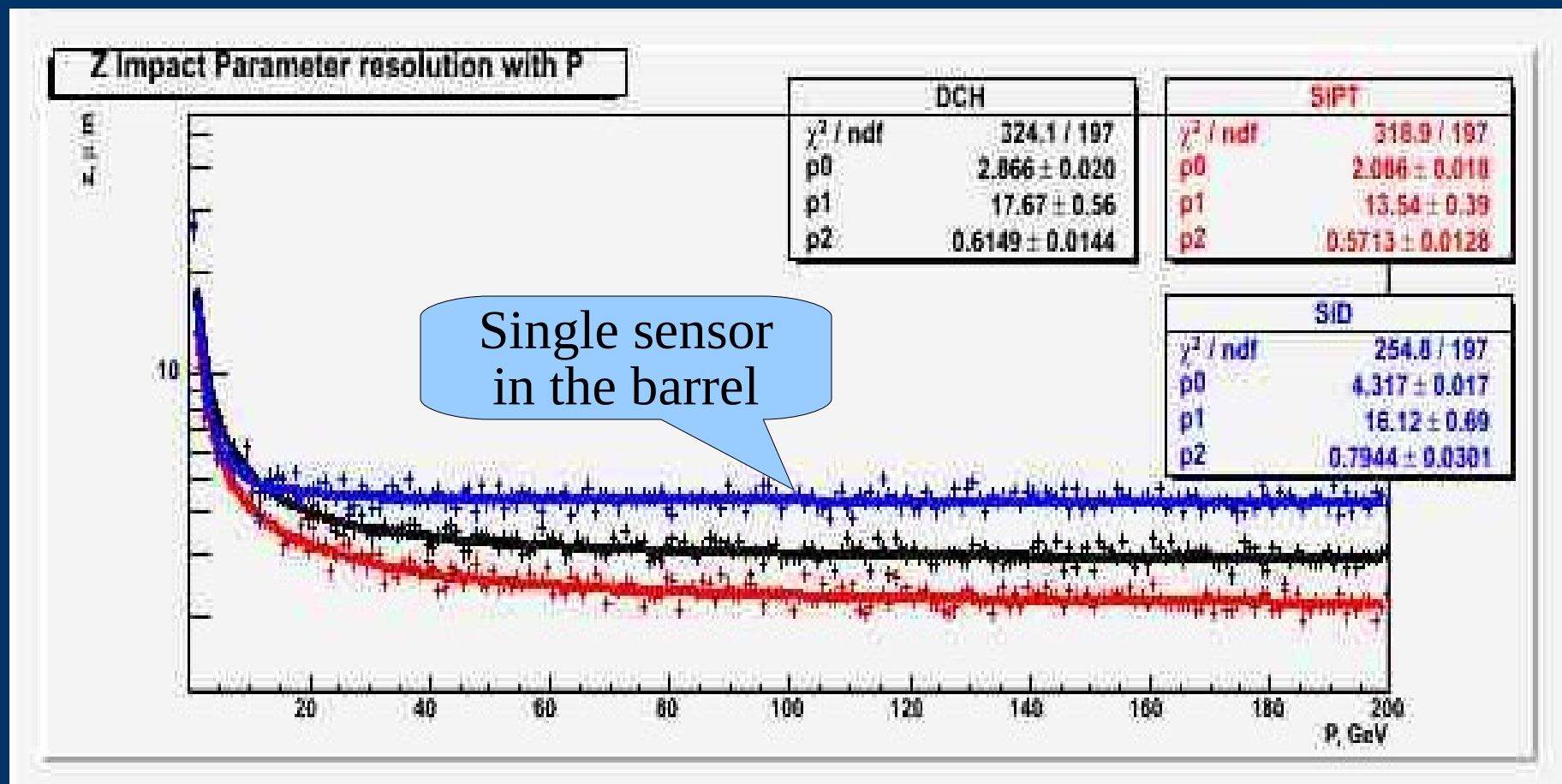




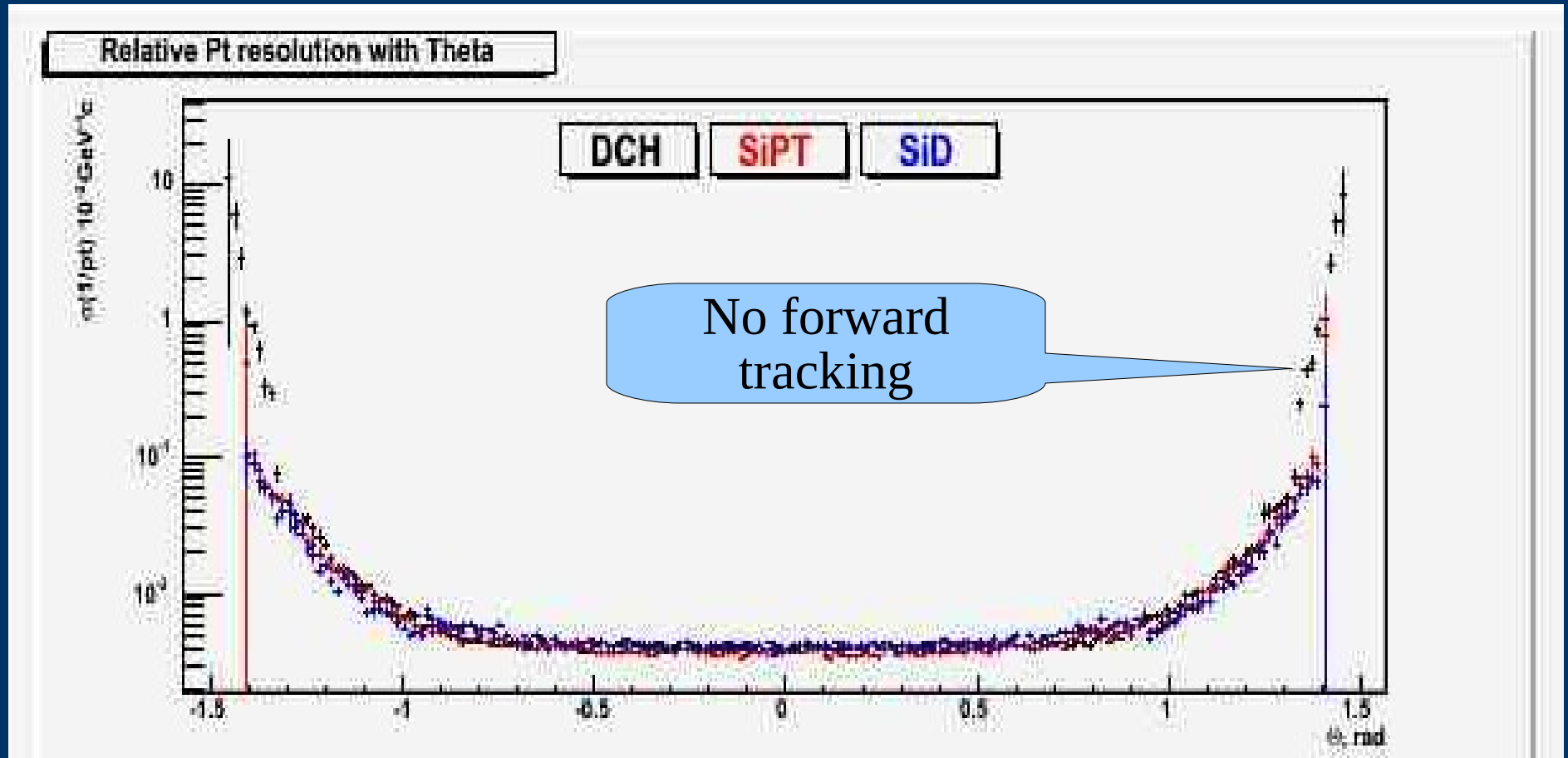
# Tracking Performance $D_0$ vs $P$



# Tracking Performance Z vs P

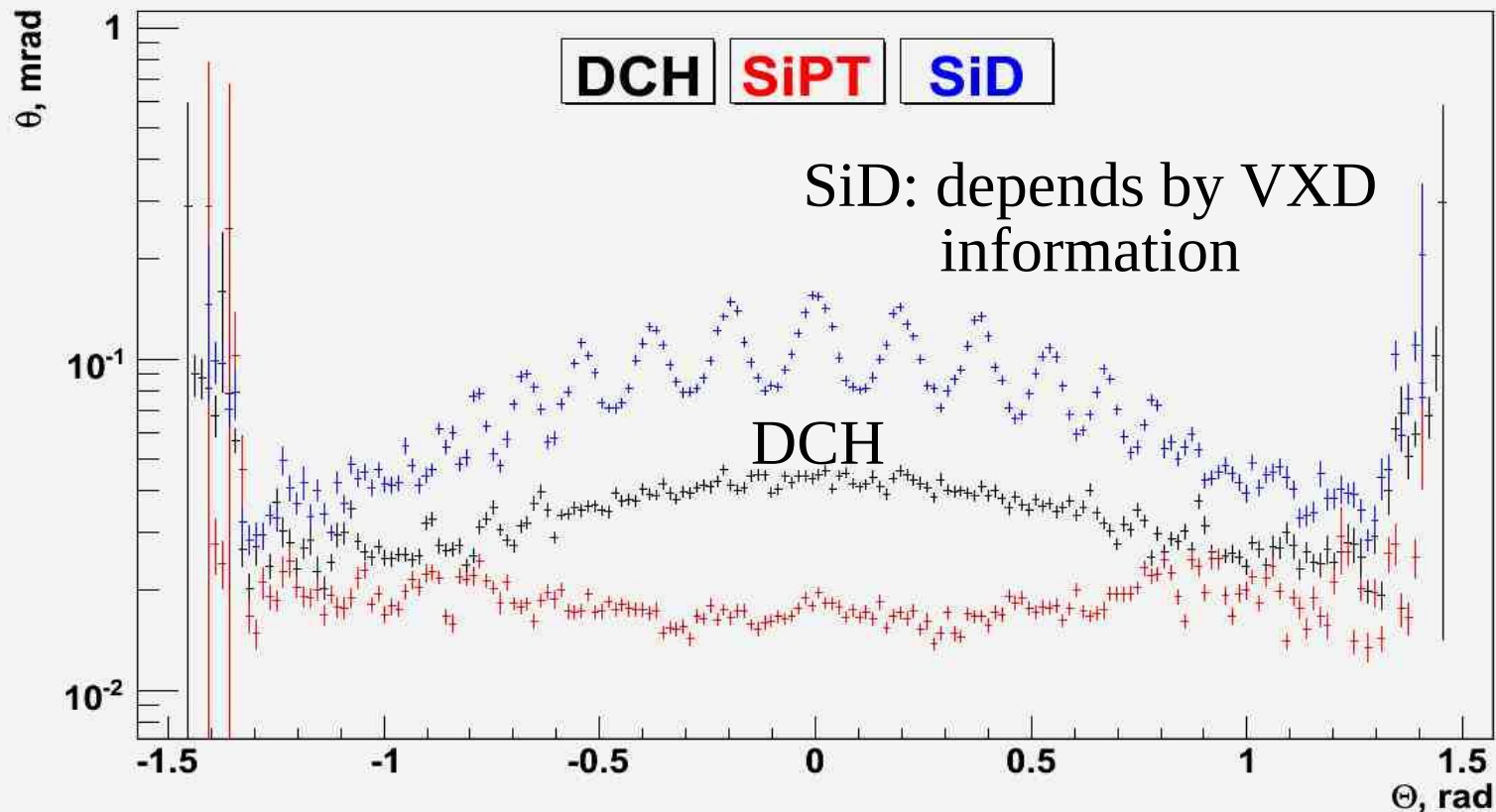


# Tracking Performance Pt Vs Theta

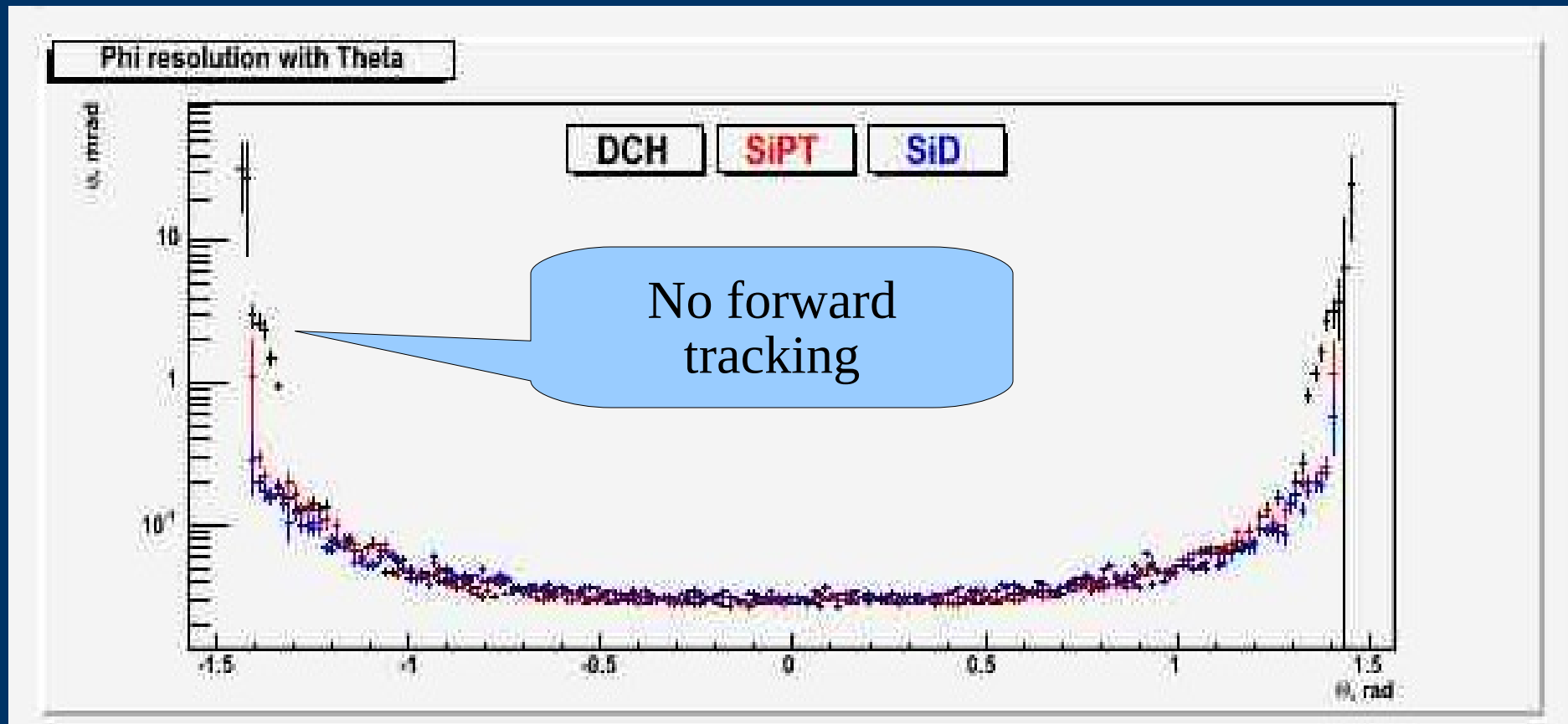


# Tracking Performance Theta Vs Theta

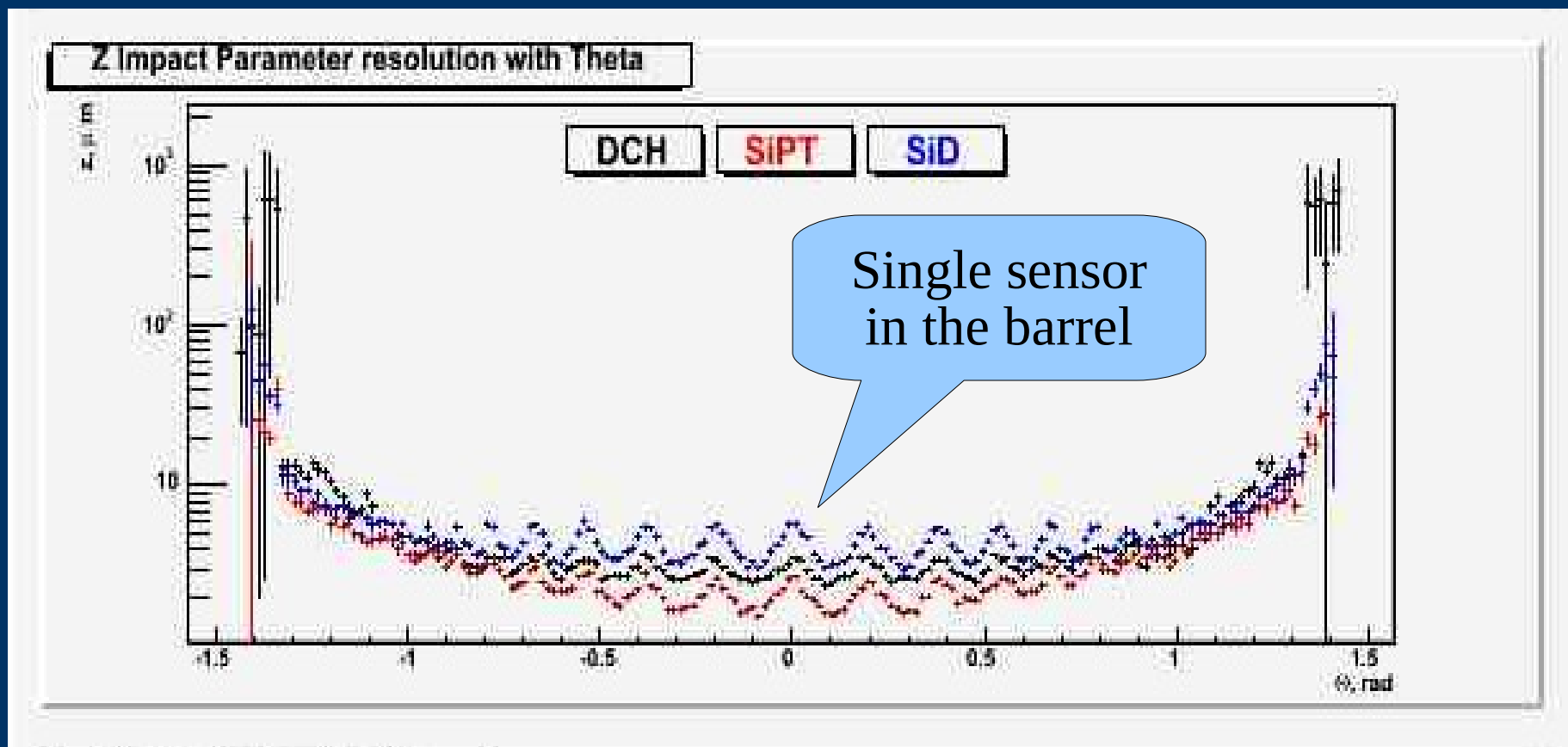
Theta resolution with Theta



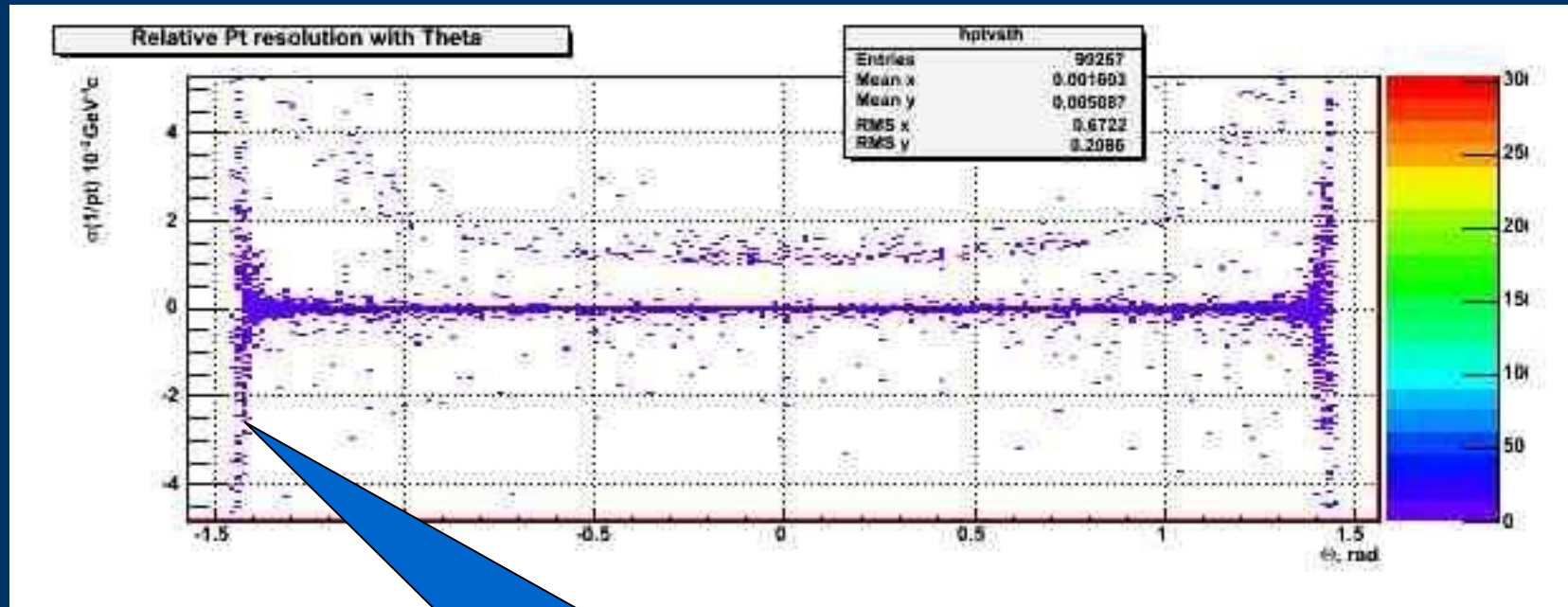
# Tracking Performance Phi Vs theta



# Tracking Performance Z Vs Theta

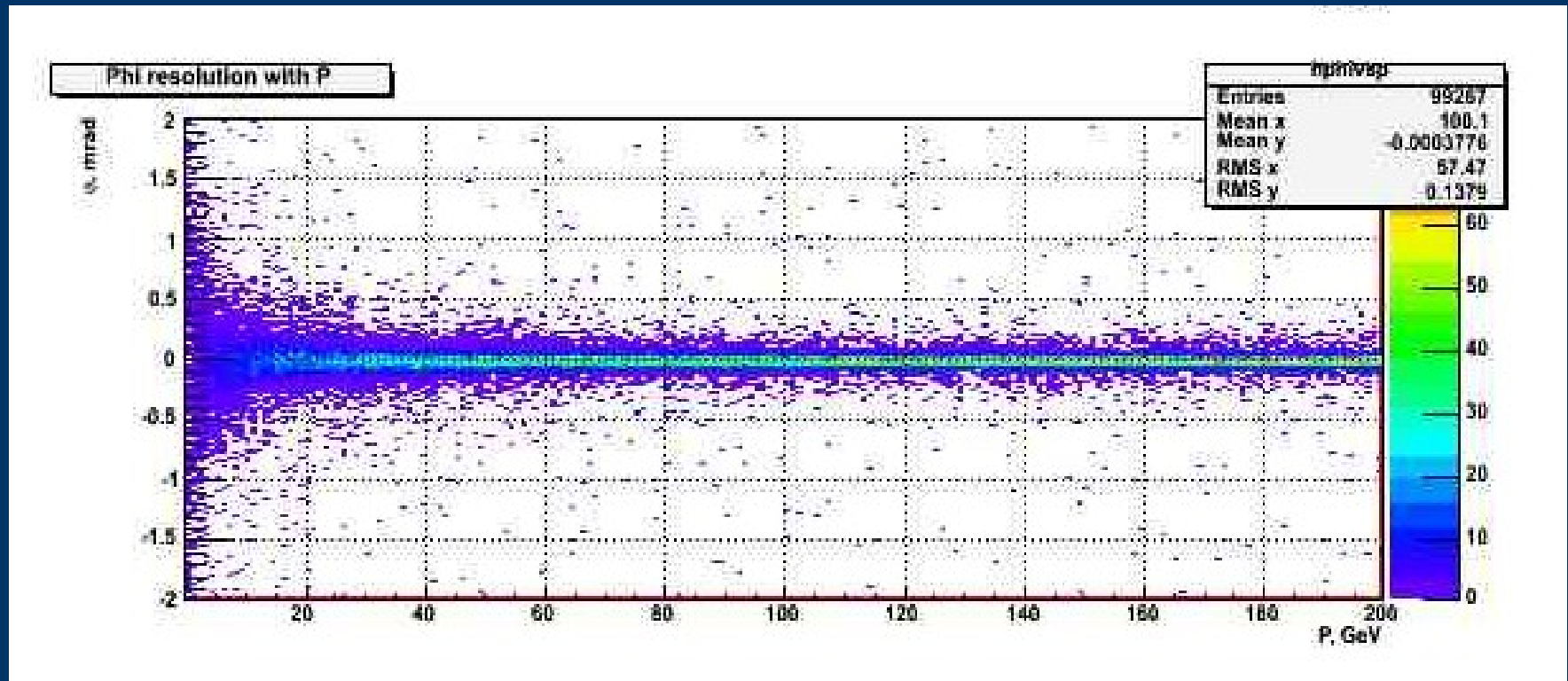


# Studies of Resolution DCH Pt Vs Theta



Limited resolution and efficiency at small angle!

# Studies of Resolution $\Phi$ Vs $P$ DCH

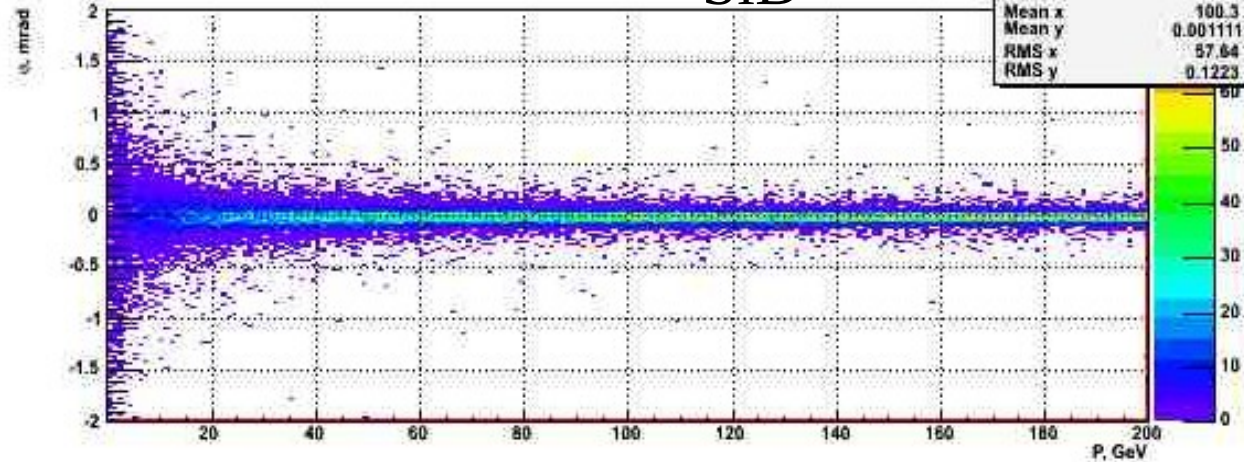




# Studies of Resolution $\Phi$ Vs $P$ SiD & SiPT

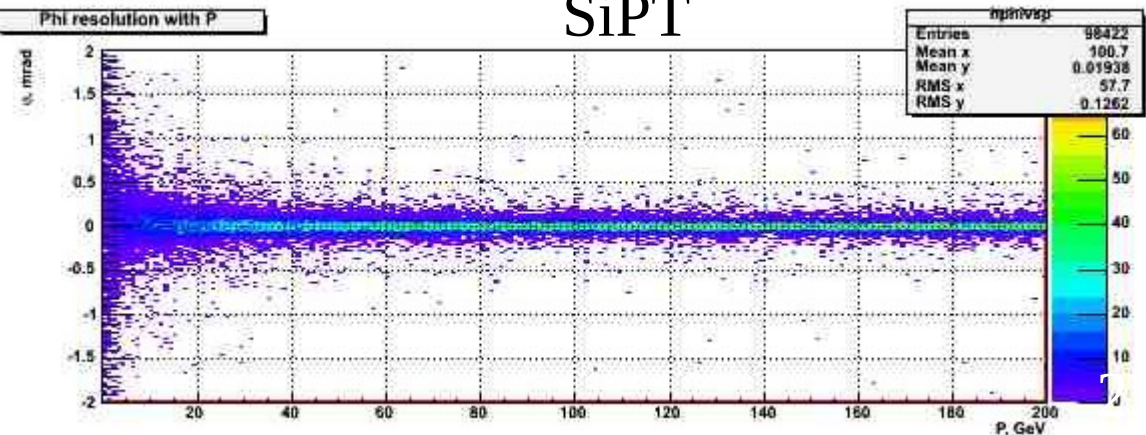
Phi resolution with P

SiD

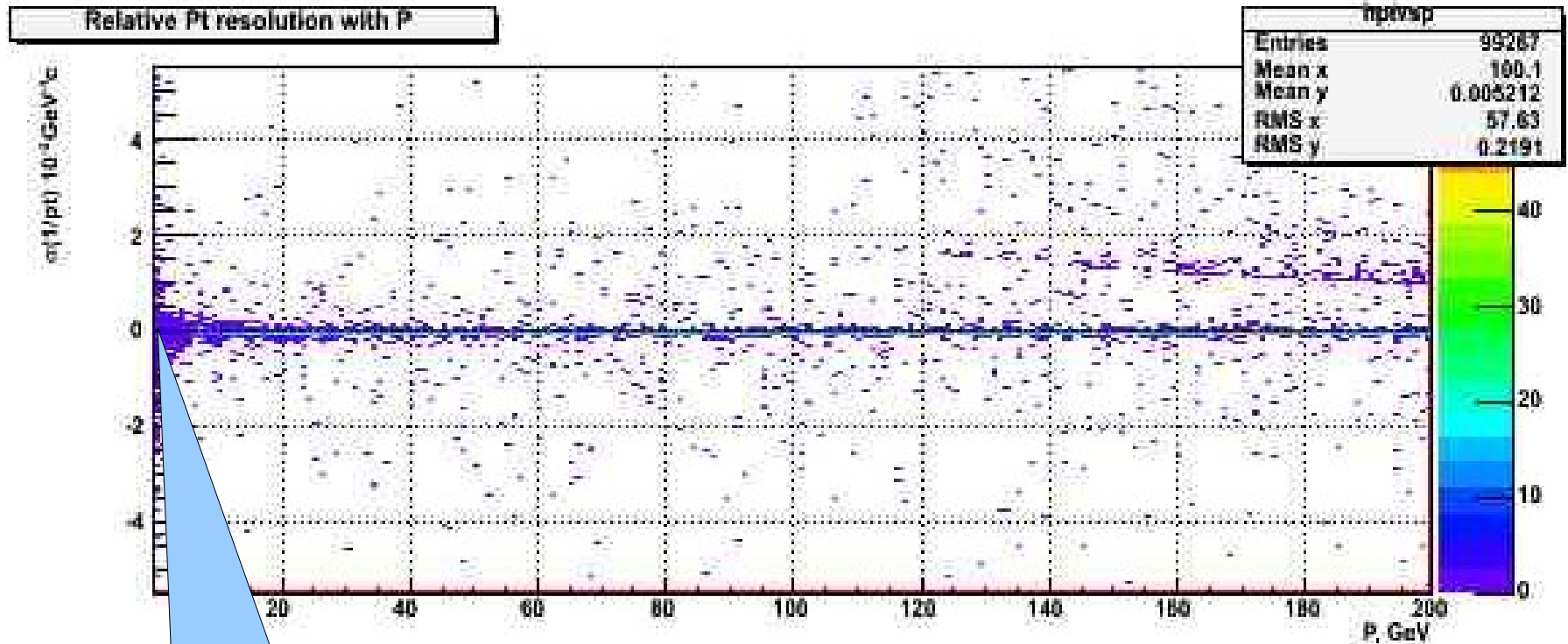


Phi resolution with P

SiPT

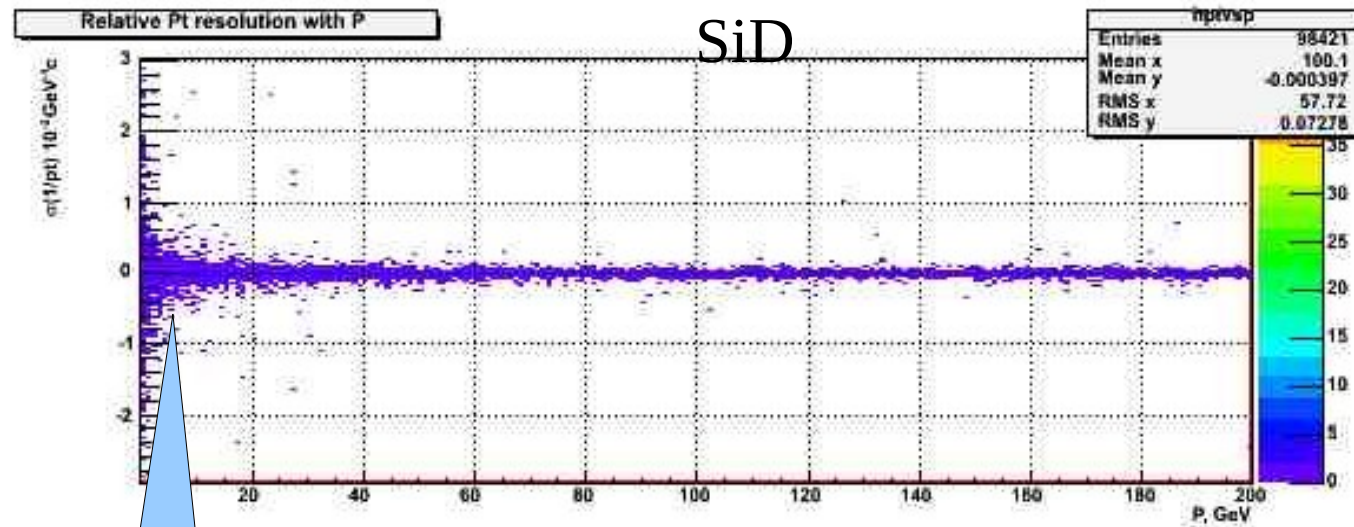


# Studies of Resolution $P$ Vs $Pt$ DCH

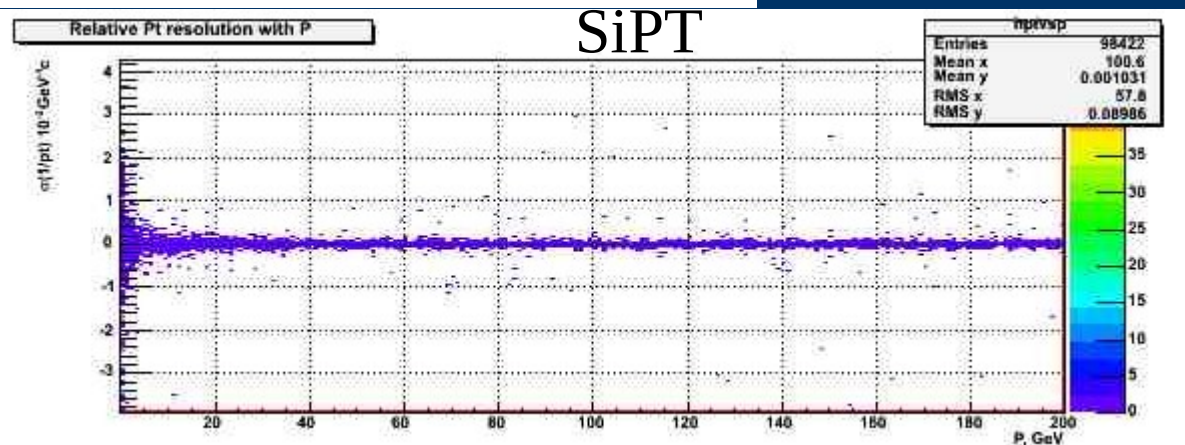


Lower ms effect!

# Studies of Resolution $P$ Vs $Pt$ SiD & SiPT



High ms effect



# Tracking Performance

Reduced ms effect

Drift Chamber

$$\begin{aligned}\sigma(P_t^{-1}) &= 7.9 / P \oplus 0.39 \times 10^{-4} \text{ GeV}^{-1} c \\ \sigma(\vartheta) &= 0.62 / P^{0.79} \oplus 0.027 \text{ mrad} \\ \sigma(\varphi) &= 1.30 / P \oplus 0.031 \text{ mrad} \\ \sigma(D_o) &= 12.8 / P^{0.46} \oplus 2.1 \mu\text{m} \\ \sigma(Z_o) &= 15.7 / P^{0.58} \oplus 2.9 \mu\text{m}\end{aligned}$$

3.5T - 5T

Si Pixel

$$\begin{aligned}\sigma(P_t^{-1}) &= 20.4 / P \oplus 0.29 \times 10^{-4} \text{ GeV}^{-1} c \\ \sigma(\vartheta) &= 0.64 / P^{0.78} \oplus 0.002 \text{ mrad} \\ \sigma(\varphi) &= 1.41 / P \oplus 0.027 \text{ mrad} \\ \sigma(D_o) &= 12.7 / P^{0.61} \oplus 2.1 \mu\text{m} \\ \sigma(Z_o) &= 13.5 / P^{0.57} \oplus 2.1 \mu\text{m}\end{aligned}$$

Many Sensors

High ms effect

Si Strips

$$\begin{aligned}\sigma(P_t^{-1}) &= 24.1 / P \oplus 0.31 \times 10^{-4} \text{ GeV}^{-1} c \\ \sigma(\vartheta) &= 0.6 / P^{0.83} \oplus 0.07 \text{ mrad} \\ \sigma(\varphi) &= 1.4 / P \oplus 0.029 \text{ mrad} \\ \sigma(D_o) &= 12.2 / P^{0.55} \oplus 2.1 \mu\text{m} \\ \sigma(Z_o) &= 16.8 / P^{0.84} \oplus 4.4 \mu\text{m}\end{aligned}$$

Single Sensor

# Summary

- *We performed compared studies using ILCRoot, simulating events with single track.*
- *The performance are inline with aspected value, the DCH works better with track with low Pt (lower ms).*
- *A new development will introduce silicon in the EndCaps region.*
- *Recostruction efficiency is very similar for each detectors.*
- *SiPT has exceptional resolution, clearly 50x50um is overkilling.*
- *SiD overall performance is very good but limited informations in the barrel region.*

# *Thanks to...*

...YOU, for your patience at my first talk.  
Corrado Gatto and his group (INFN - Italy)  
Prof. Franco Grancagnolo and his group (INFN - Italy)  
Fedor V. Ignatov (BINP - Russia)  
Alexander Charpy (LPNHEP-France)  
Fermi National Laboratory

and a special thanks to the 10muons!

# *Backup Slide: The problem along Z coordinates in VXD*

